

## **Standard Rectifier Module**

# PHASE OUT

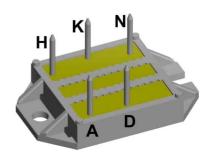
3~ Rectifier Bridge

Phase out

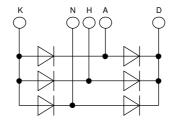
3~ Rectifier					
$V_{\text{RRM}}$	=	1400	٧		
$I_{\text{DAV}}$	=	90	Α		
$I_{FSM}$	=	550	Α		

Part number

VUO86-14NO7







#### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

#### **Applications:**

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: ECO-PAC1

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Recommended replacement: VUO86-16NO7

#### Terms and Conditions of Usage

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747 and per semiconductor unless otherwise specified

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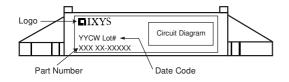
Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse bloc	cking voltage	$T_{VJ} = 25^{\circ}C$			1500	V
V <sub>RRM</sub>	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1400	٧
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1400 V	$T_{VJ} = 25^{\circ}C$			40	μΑ
		$V_R = 1400 \text{ V}$	$T_{VJ} = 150$ °C			1.5	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 30 A	$T_{VJ} = 25^{\circ}C$			1.14	٧
		$I_F = 90 A$				1.48	V
		$I_F = 30 \text{ A}$	T <sub>VJ</sub> = 125°C			1.06	٧
		$I_F = 90 A$				1.51	٧
IDAV	bridge output current	T <sub>C</sub> = 105°C	T <sub>vJ</sub> = 150°C			90	Α
		rectangular d = ⅓					i ! !
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 150°C			0.81	V
r <sub>F</sub>	slope resistance } for power	loss calculation only				7.8	mΩ
R <sub>thJC</sub>	thermal resistance junction to ca	ase				0.9	K/W
R <sub>thCH</sub>	thermal resistance case to heats	sink			0.4		K/W
P <sub>tot</sub>	total power dissipation		$T_{\text{C}} = 25^{\circ}\text{C}$			135	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			550	Α
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			595	Α
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			470	Α
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			505	Α
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			1.52	kA2s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.48	kA2s
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			1.11	kA2s
		t = 8.3  ms; (60 Hz), sine	$V_R = 0 V$			1.06	kA2s
CJ	junction capacitance	$V_{R} = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		18		pF

# PHASE OUT





Package ECO-PAC1			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal				100	Α
T <sub>VJ</sub>	virtual junction temperature			-40		150	°C
T <sub>op</sub>	operation temperature			-40		125	°C
T <sub>stg</sub>	storage temperature					125	°C
Weight					19		g
M <sub>D</sub>	mounting torque			1.4		2	Nm
d <sub>Spp/App</sub>	creepage distance on surface   striking distance through air		terminal to terminal	6.0			mm
$d_{Spb/Apb}$			terminal to backside	10.0			mm
V <sub>ISOL</sub>	isolation voltage	t = 1 second		3000			٧
	t = 1 minute		50/60 Hz, RMS; lisoL ≤ 1 mA	2500			٧

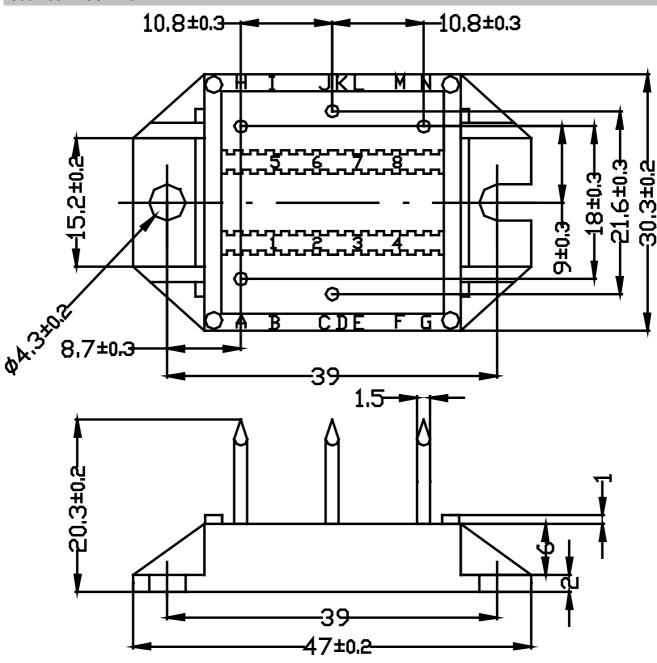


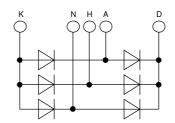
C	Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
S	Standard	VUO86-14NO7	VUO86-14NO7	Box	25	491802

<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 150 ^{\circ}\text{C}$
$I \rightarrow V_0$	)—[R <sub>0</sub> ]-	Rectifier		
V <sub>0 max</sub>	threshold voltage	0.81		V
$R_{0 \text{ max}}$	slope resistance *	6.6		$m\Omega$



#### Outlines ECO-PAC1





#### Rectifier

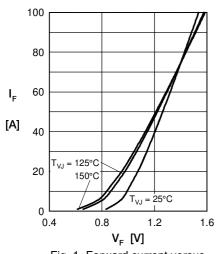


Fig. 1 Forward current versus voltage drop per diode

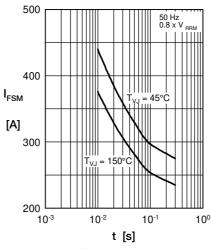


Fig. 2 Surge overload current

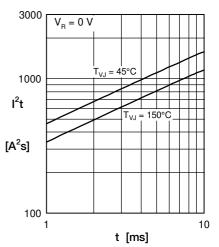


Fig. 3 I<sup>2</sup>t versus time per diode

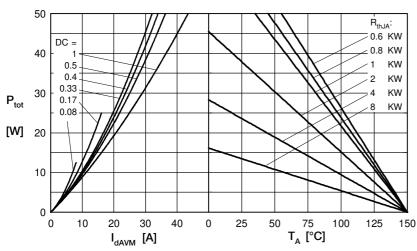


Fig. 4 Power dissipation vs. direct output current & ambient temperature

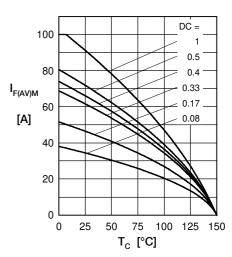


Fig. 5 Max. forward current vs. case temperature

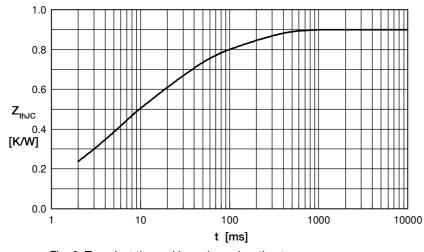


Fig. 6 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{th}$ (K/W)	t <sub>i</sub> (s)
1	0.0607	0.000
2	0.1230	0.00256
3	0.2330	0.0045
4	0.3230	0.0242
5	0 1628	0.18

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